

Phonon Transport in Periodic Materials with Feature Sizes of 1 nm to 1 μm

Alan McGaughey

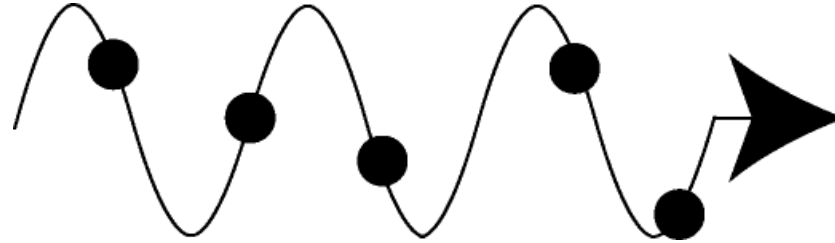
Department of Mechanical Engineering
Carnegie Mellon University, Pittsburgh PA

CMU: Ankit Jain, Jason Larkin, Eric Landry
U. Toronto: Sam Huberman, Cristina Amon

Support: NSF, AFOSR

What is a Phonon?

- Quantized lattice vibration in a periodic material with energy $\hbar\omega$



- Wave number ($=2\pi/\text{wavelength}$), frequency, and polarization
→ Define the *phonon mode*
- Primary carriers of thermal energy in semiconductors and dielectrics (Si, GaN, quartz)

Phonon Formula for Thermal Conductivity

Boltzmann transport equation + Fourier law

$$\Rightarrow k_n = \sum_i c_{v,i} v_{g,i,n}^2 \frac{\Lambda_i}{|\mathbf{v}_{g,i}|}$$

i : indexes over all phonon modes

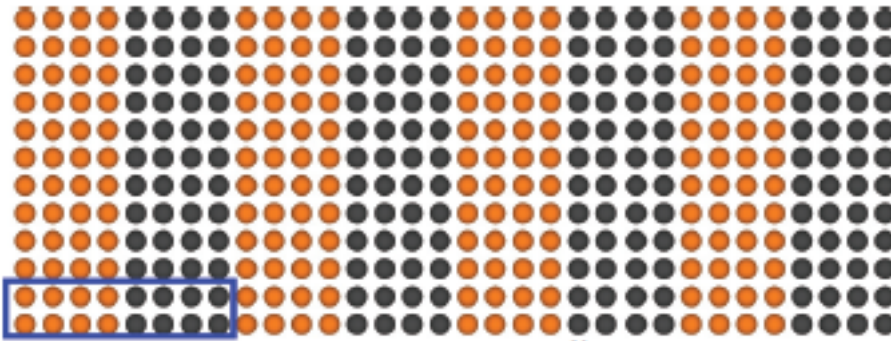
$c_{v,i}$: specific heat

$\mathbf{v}_{g,i}$: group velocity

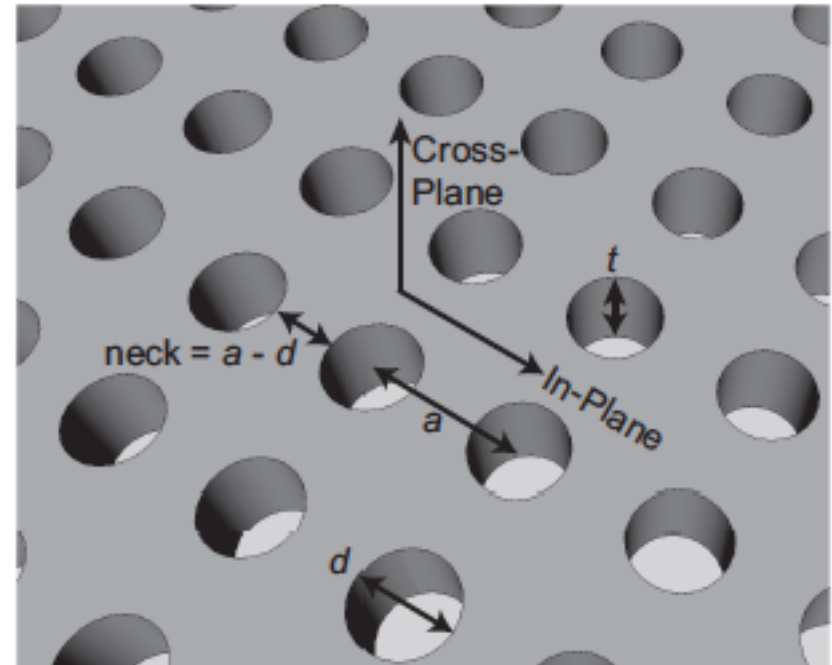
Λ_i : mean free path

Application to Periodic Materials

Superlattice

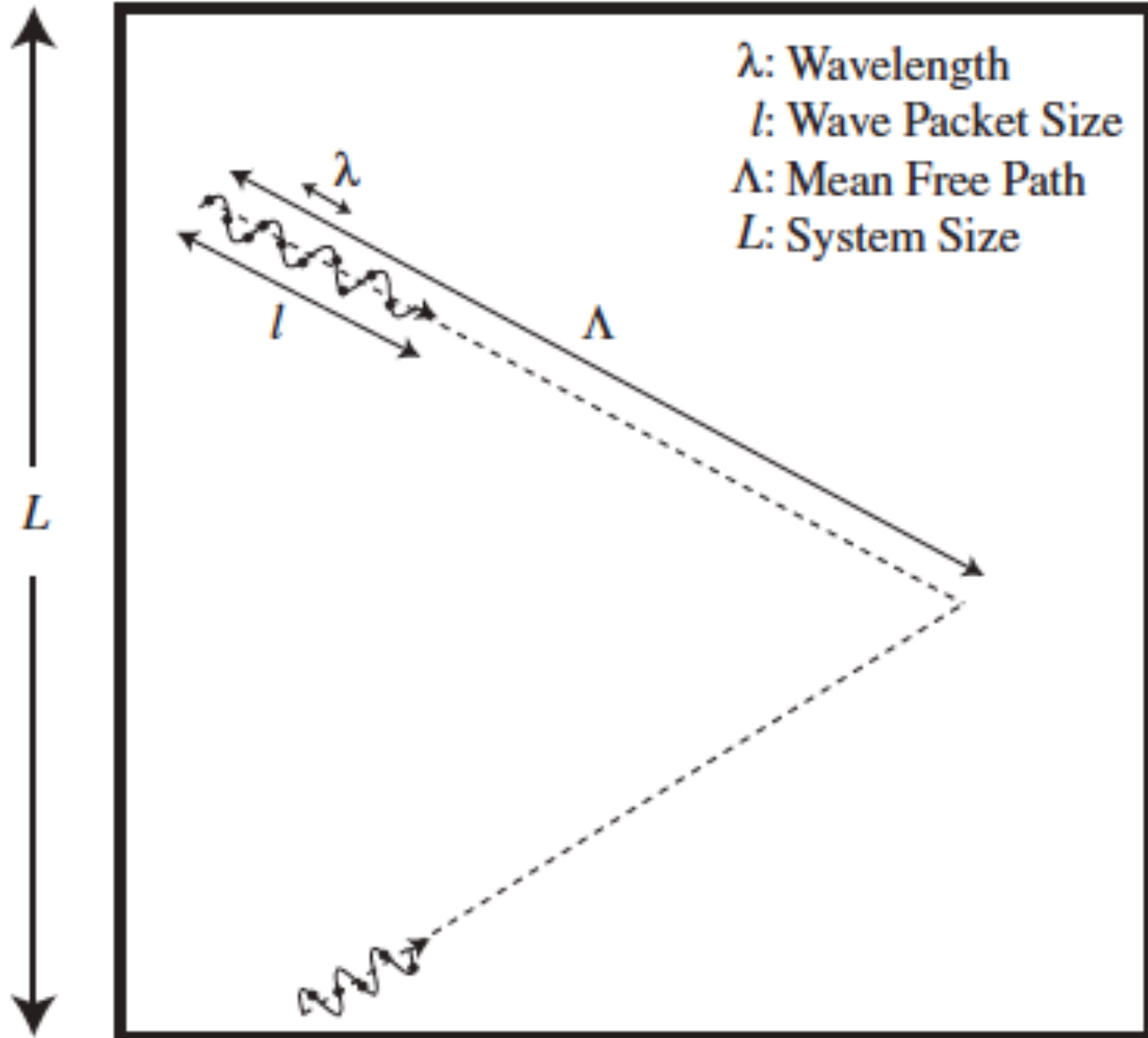


Porous Film



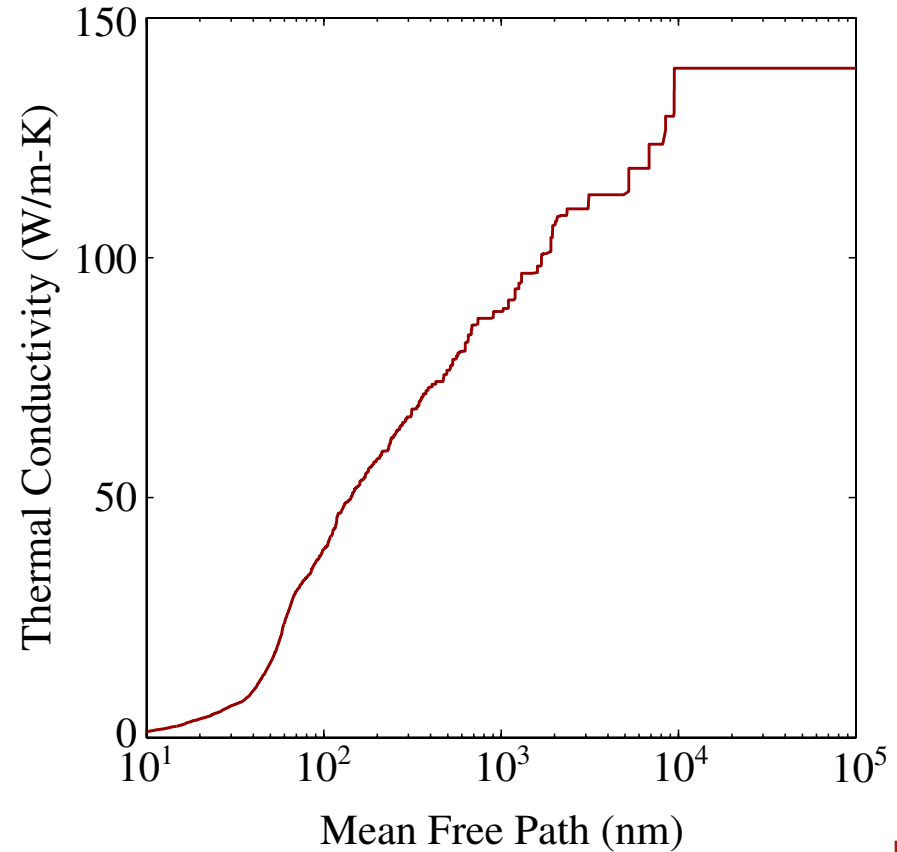
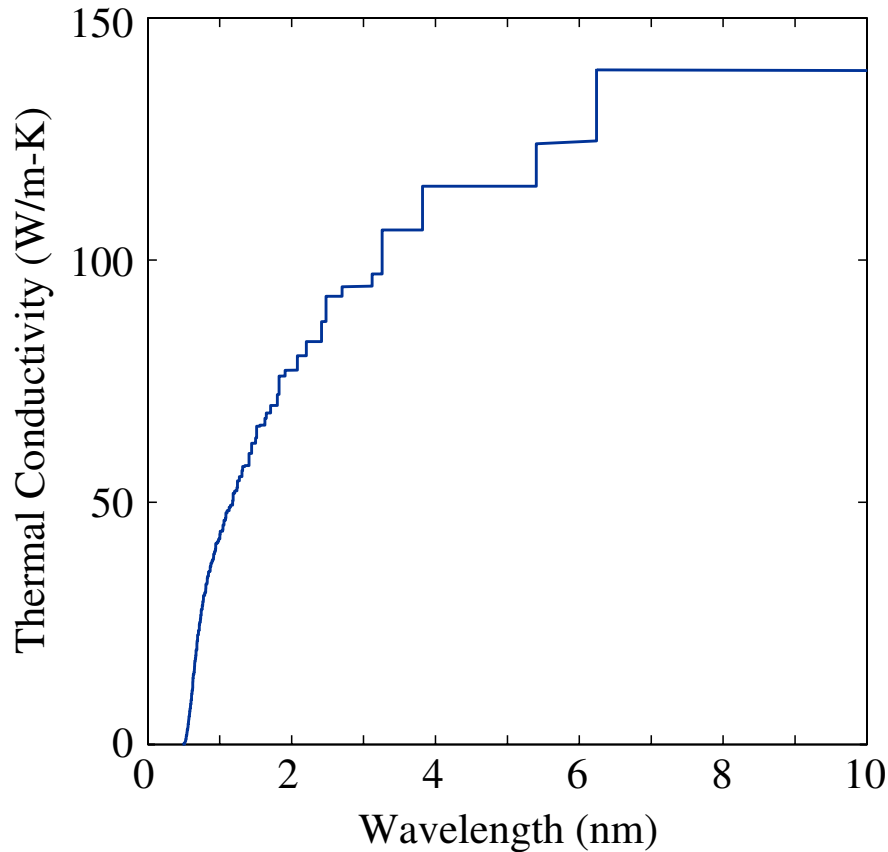
How to define the phonons?
What dispersion relation to use?

Length Scales in Phonon Transport



Bulk Silicon Accumulation

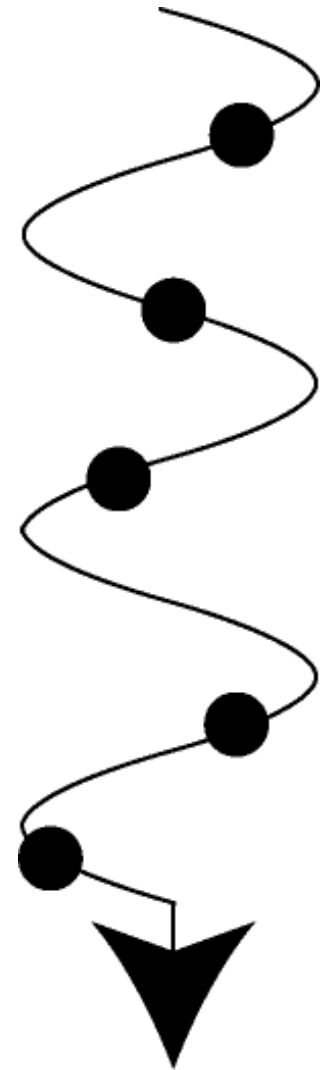
Phonon properties from first-principles calculations.



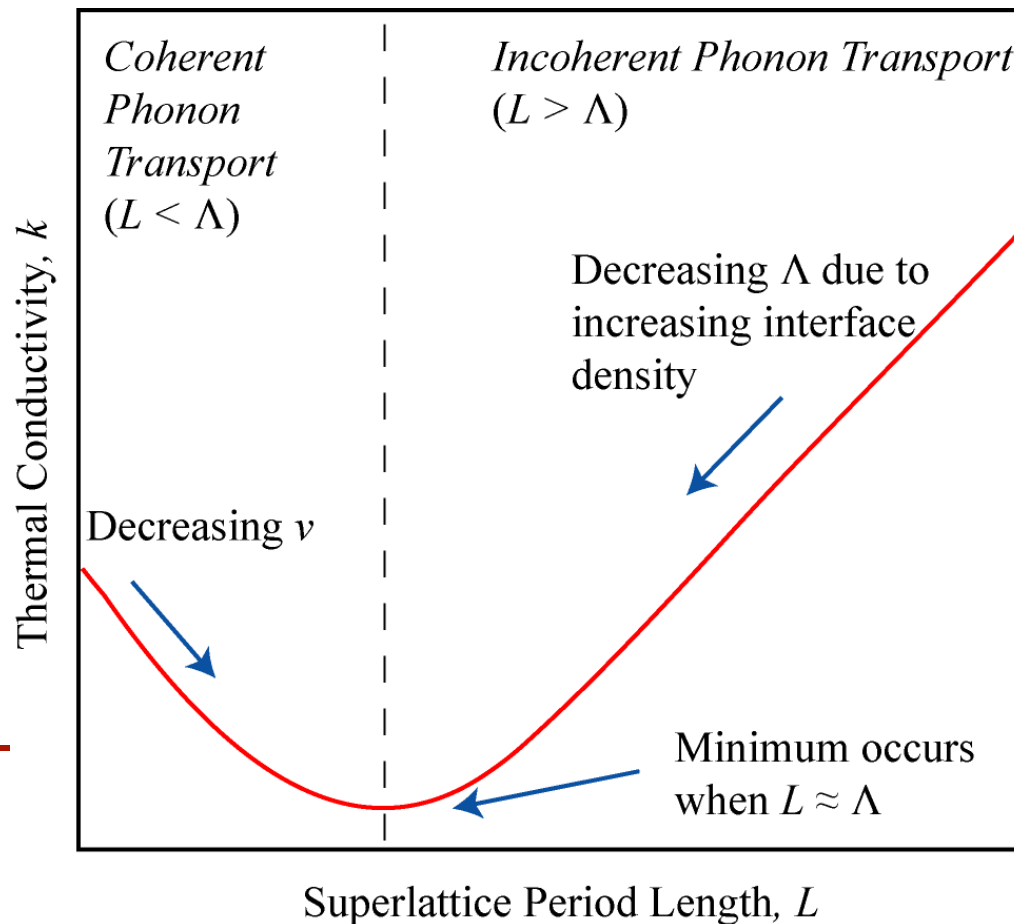
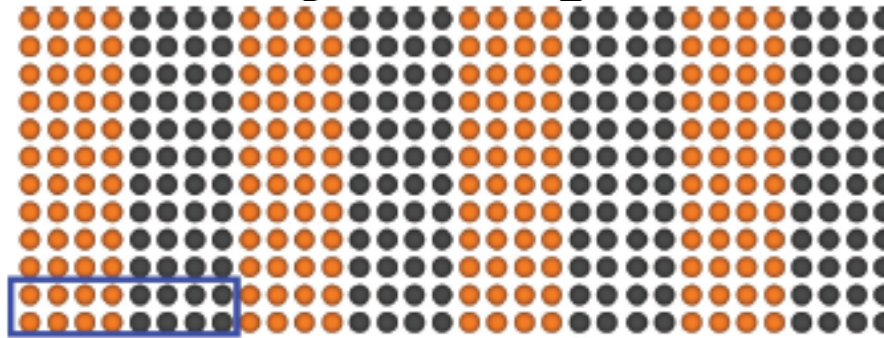
Boundary scattering important when mean free path $>$ system size.

Outline

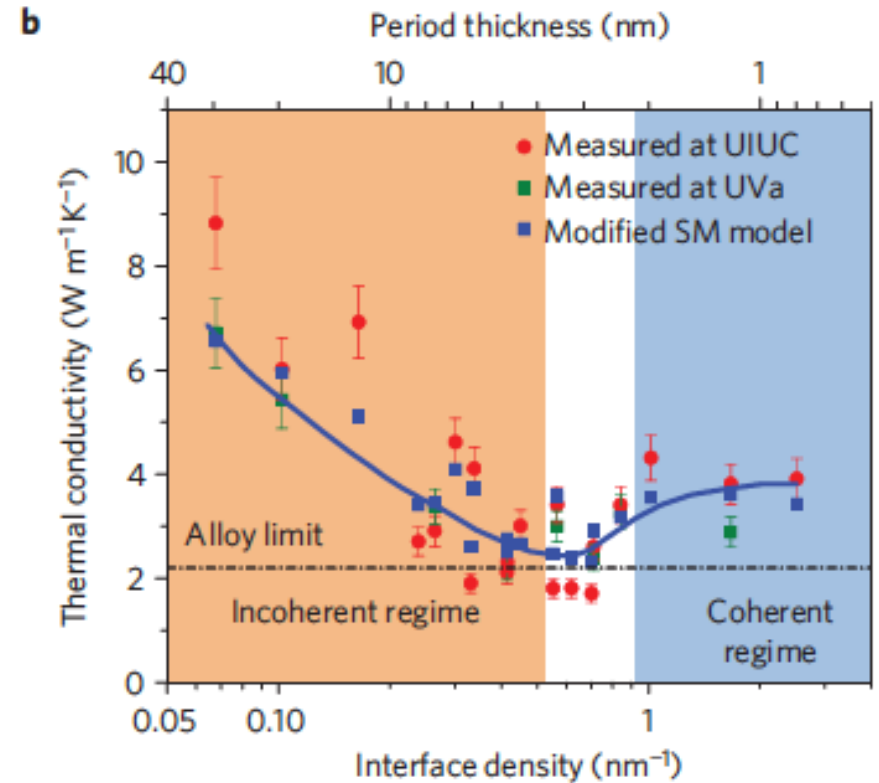
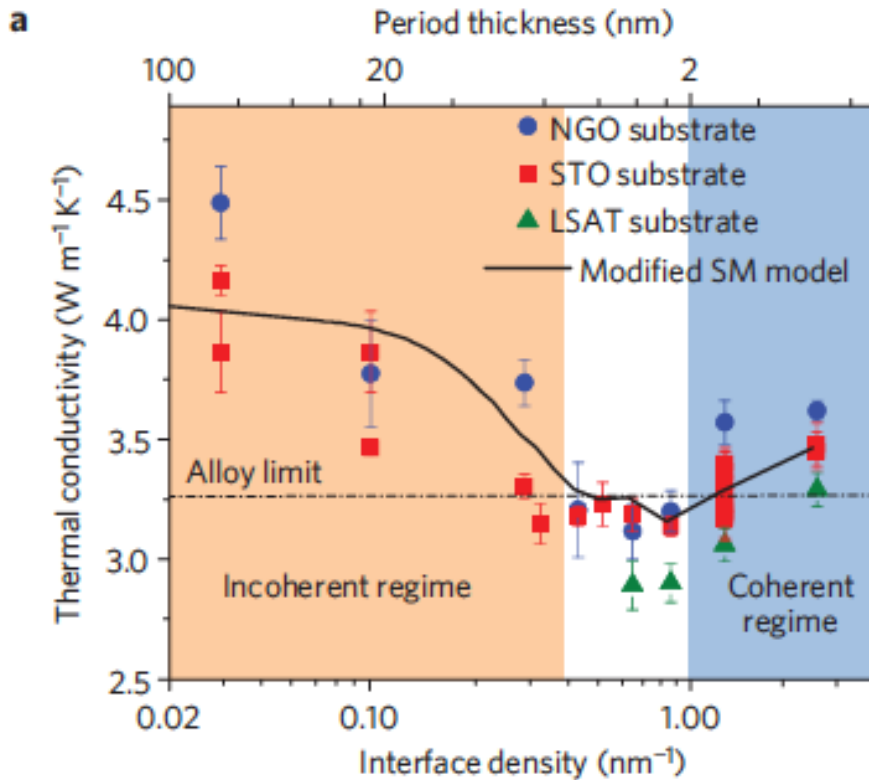
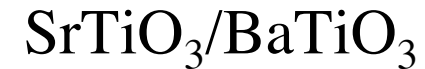
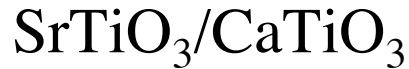
1. Introduction
2. Superlattices
3. Porous Thin Films
4. Summary



Proposed Phonon Transport Regimes

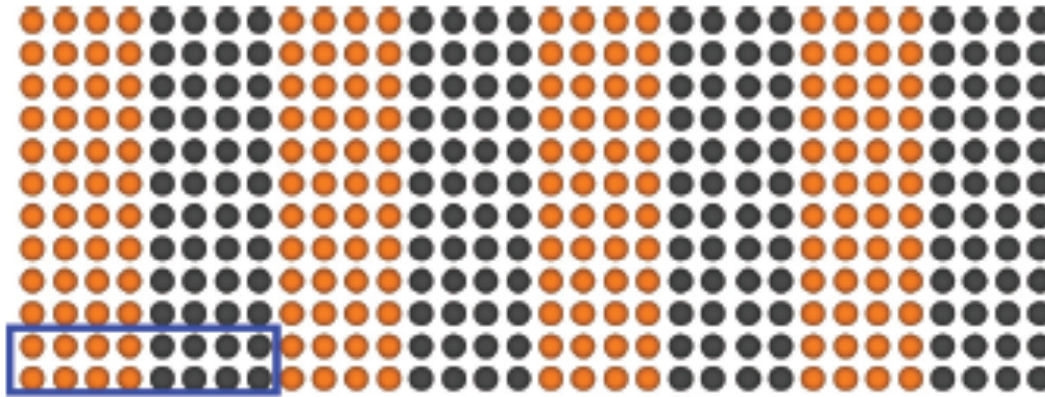


Experimental Evidence in Oxide Superlattices

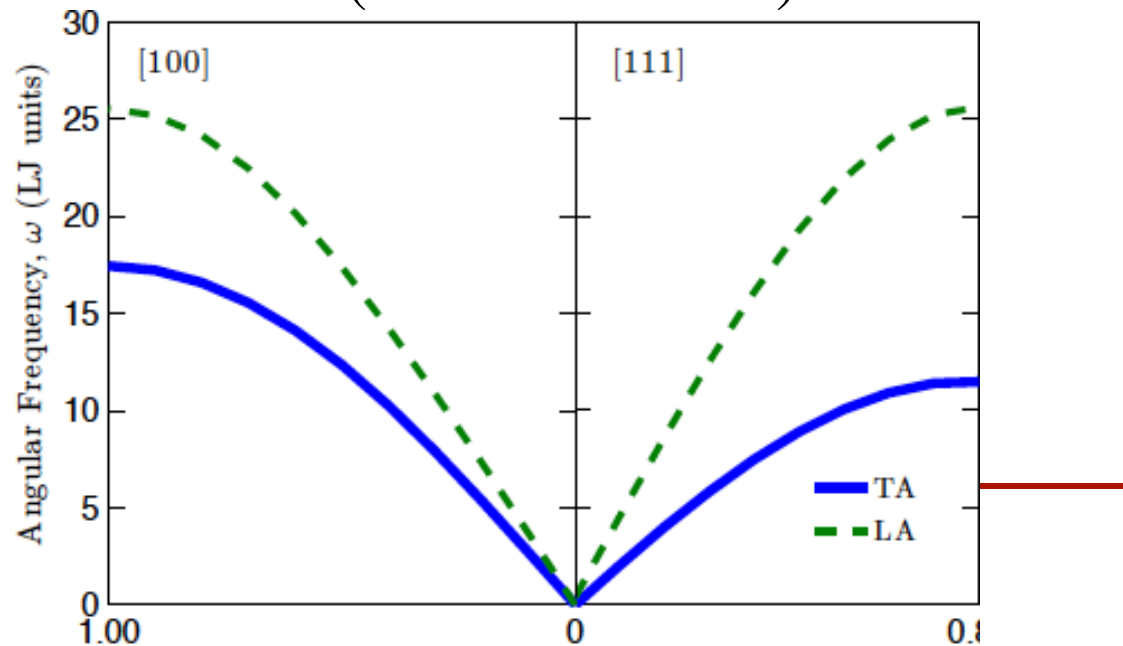


Need interfaces of extremely high quality.

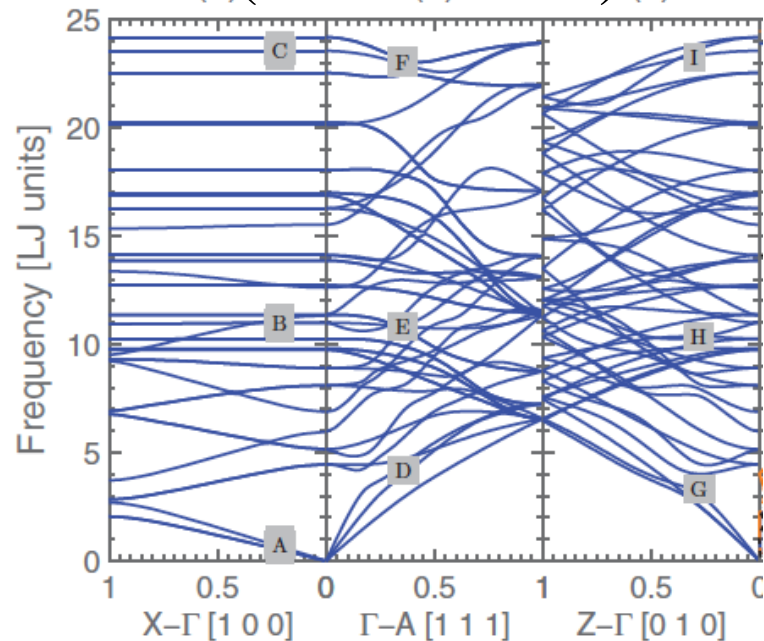
What Dispersion to Use?



Layer Lattice Constant
(INCOHERENT)



Superlattice Period
(COHERENT)



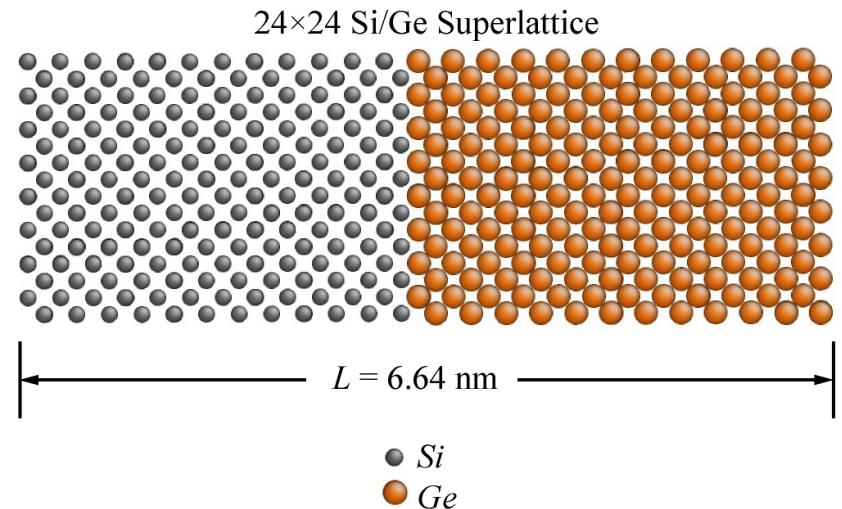
Silicon/Germanium Superlattices

Questions:

- Can we predict experimental trends?
- How does sample quality affect phonon transport?

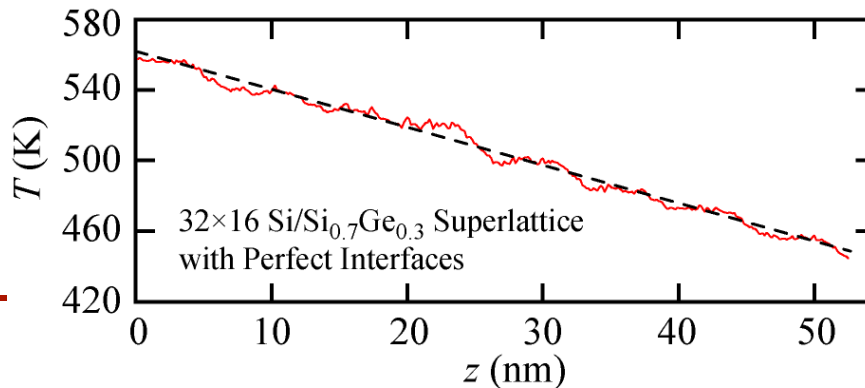
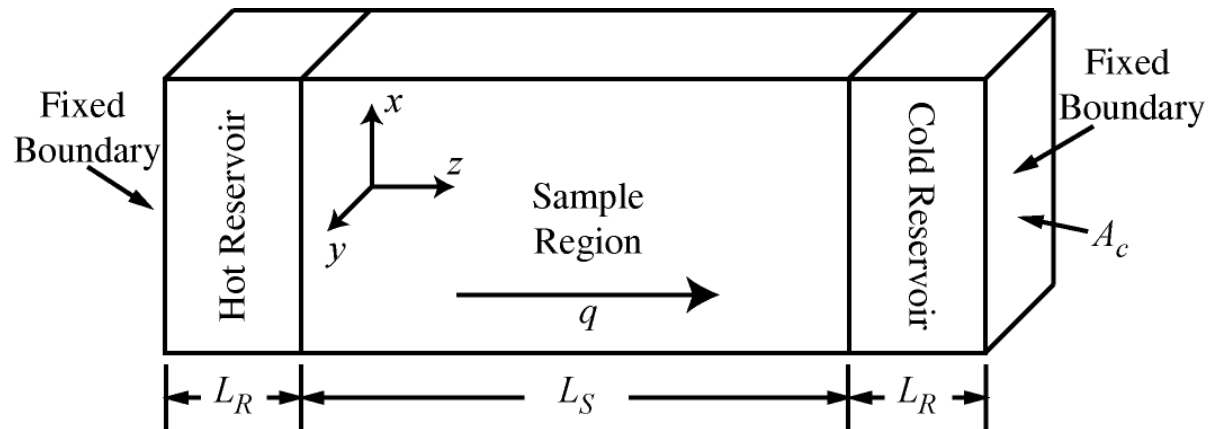
Samples:

- Si/Ge superlattices
- Stillinger-Weber potential
- $T = 500$ K



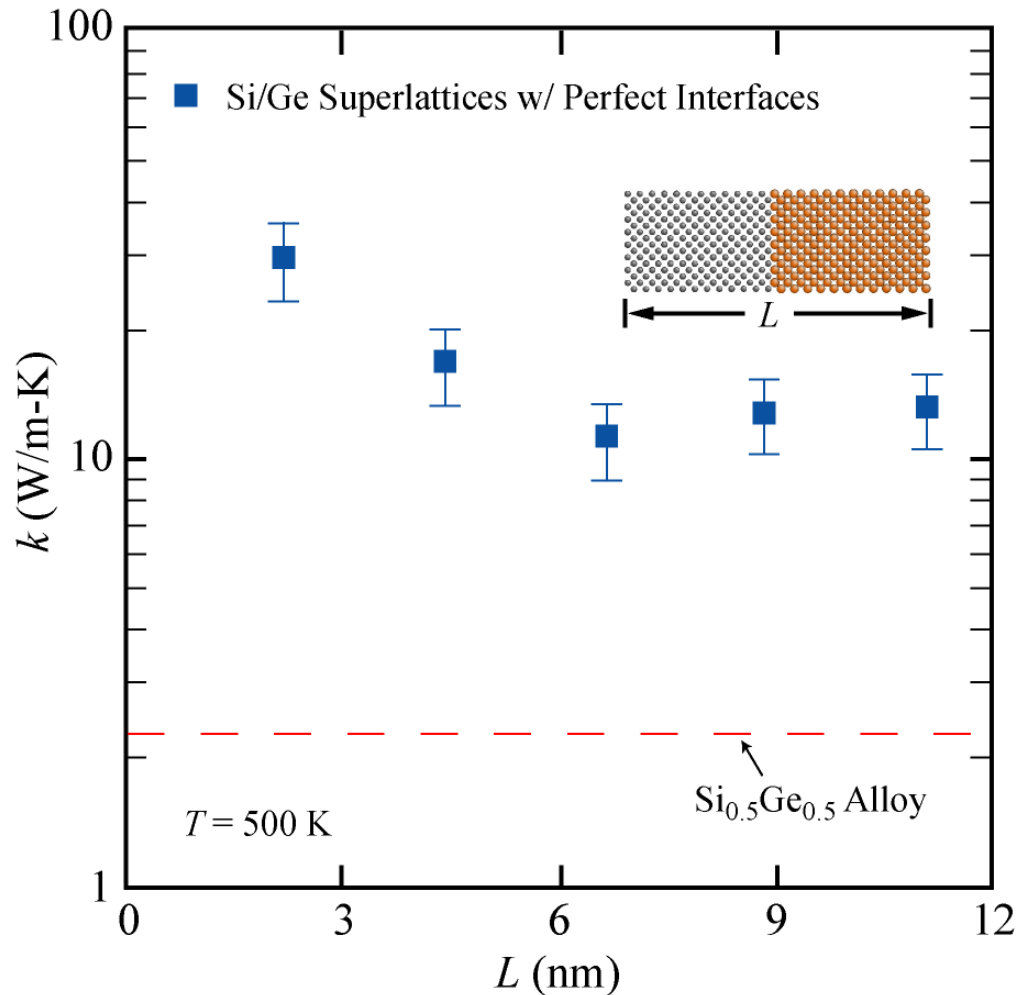
Molecular Dynamics (MD) Simulations

- Predict evolution of atomic positions/momentum using Newton's laws of motion.
- No assumptions about nature of phonon transport.



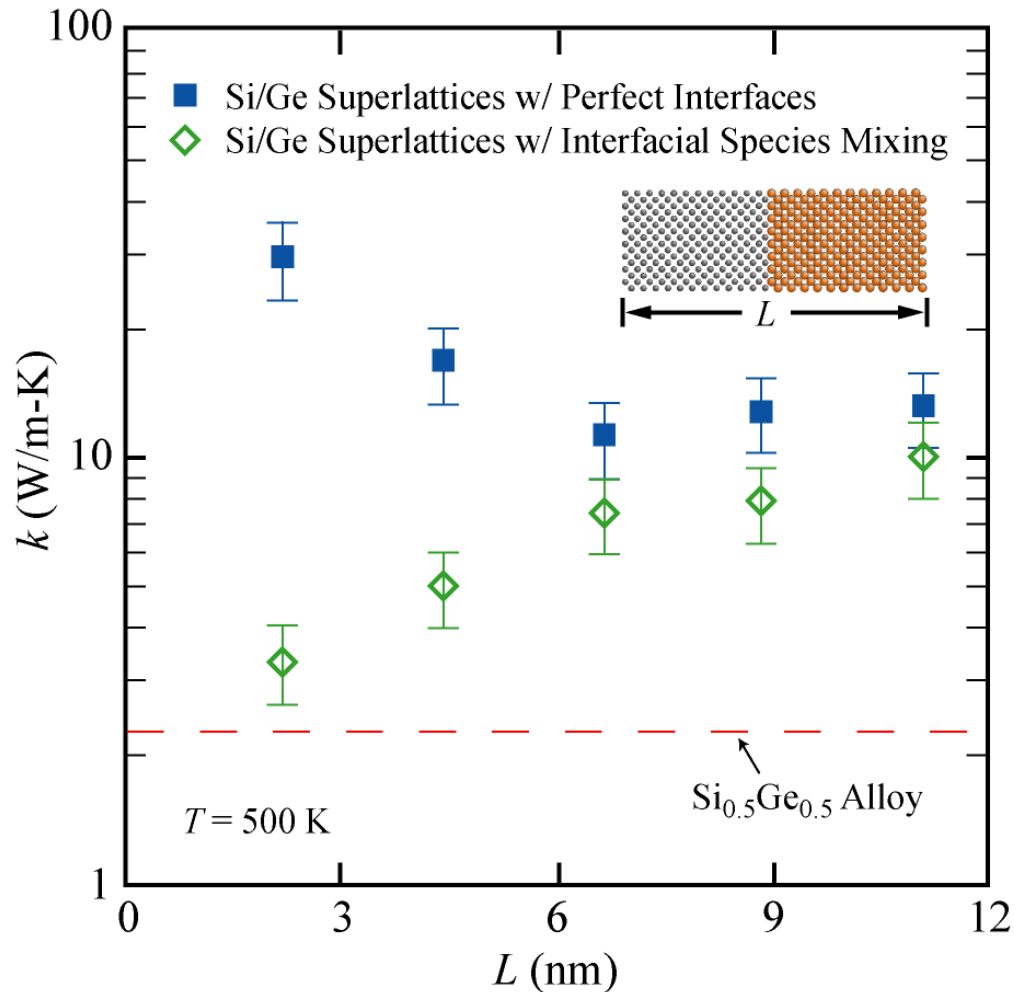
$$k = \frac{-q}{\partial T / \partial z}$$

Si/Ge Superlattices with Perfect Interfaces



Thermal conductivity *decreases* with increasing period length.

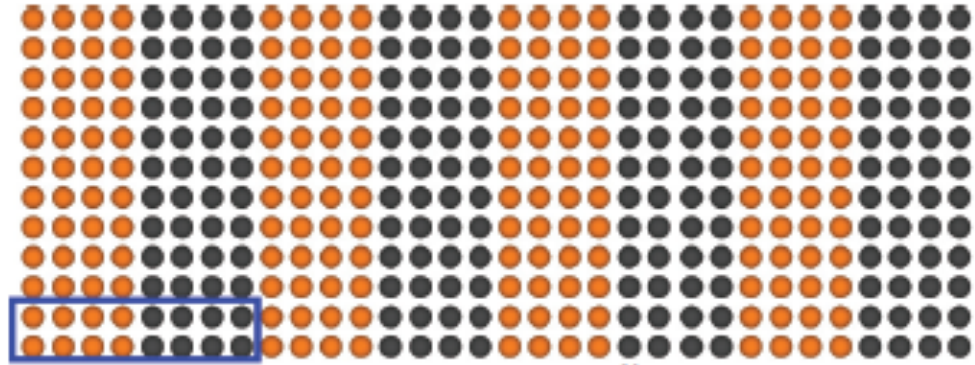
Si/Ge Superlattices with Interfacial Mixing



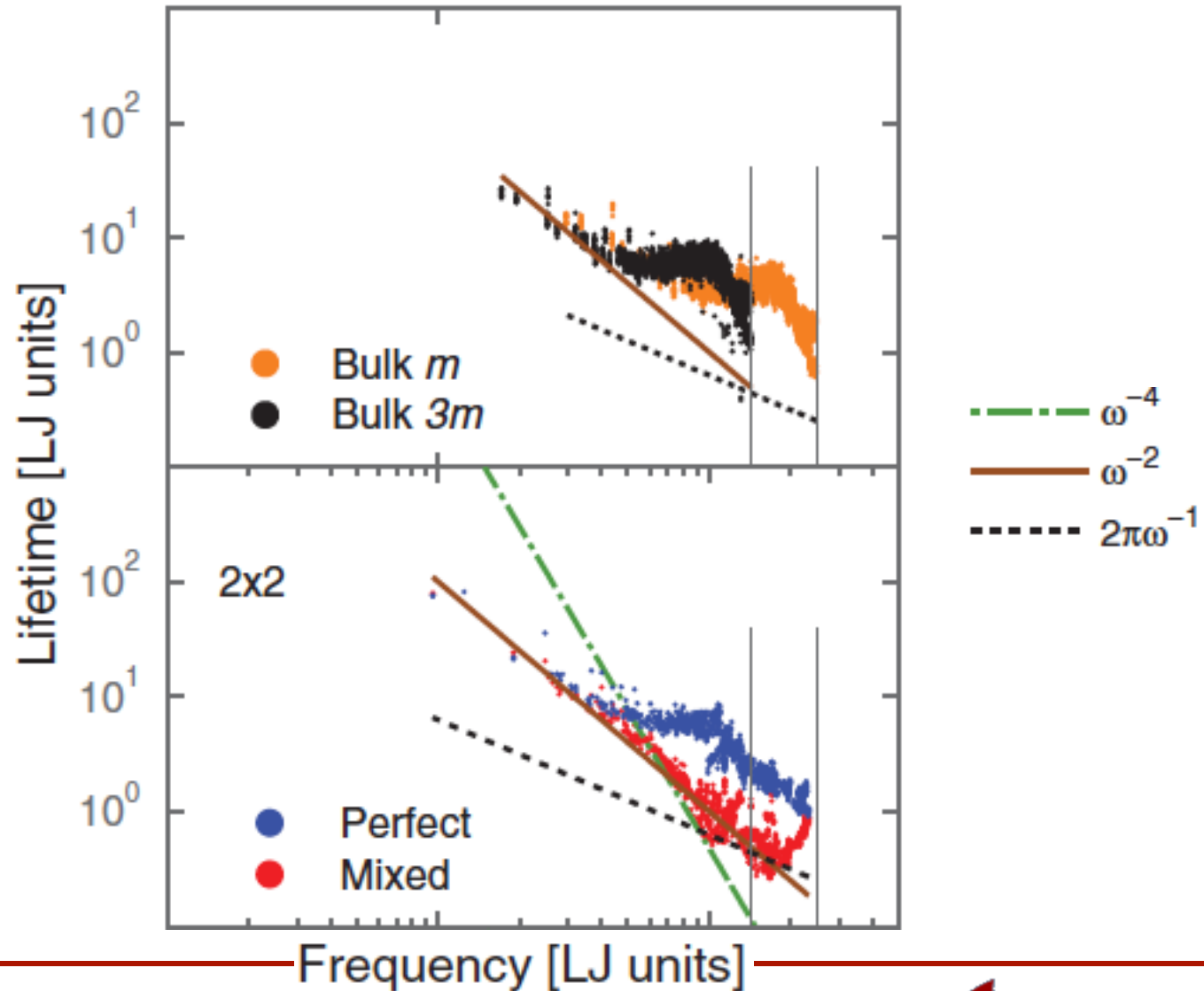
Thermal conductivity *increases* with increasing period length.

Lennard-Jones Superlattices

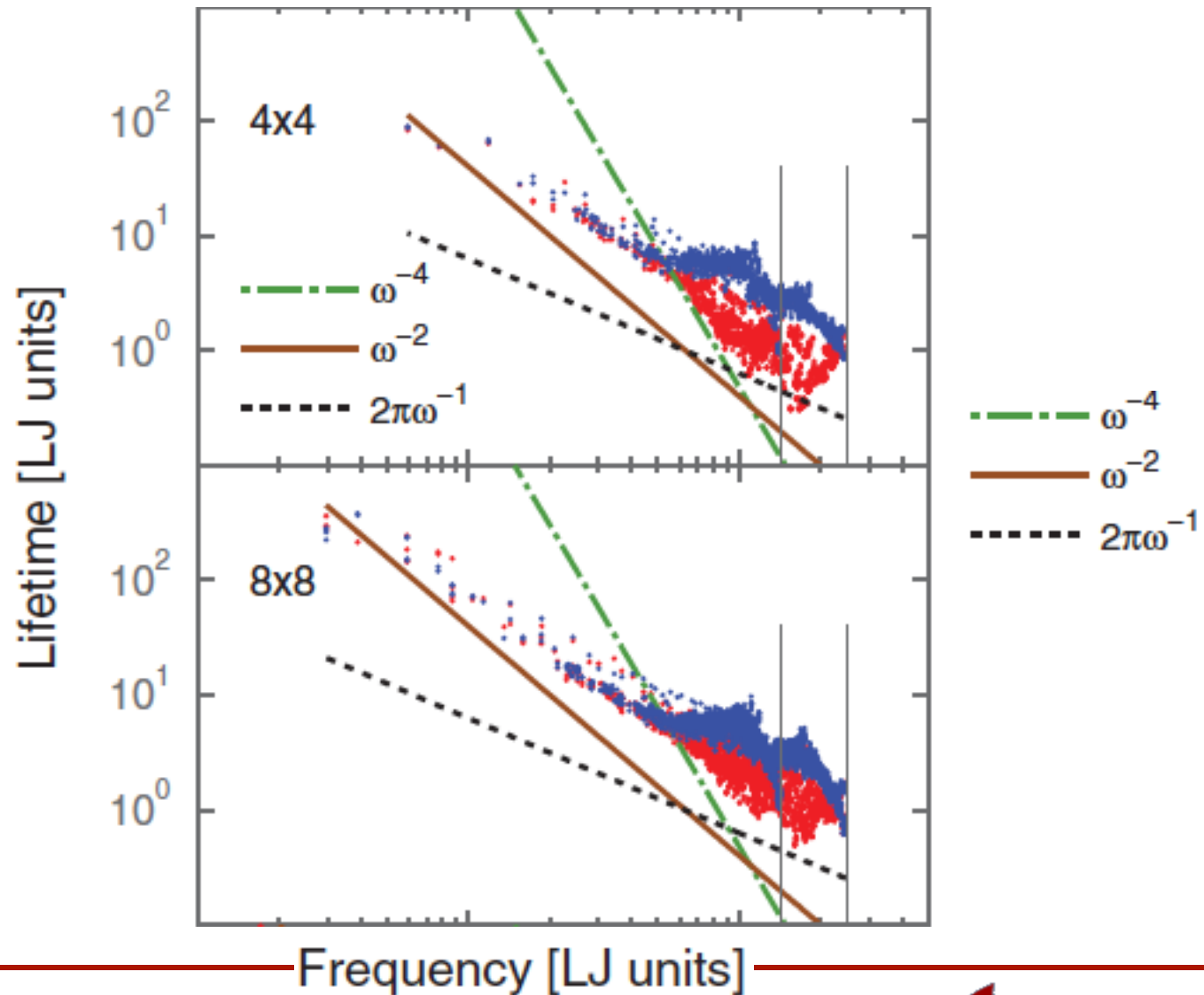
- Base: argon, $T = 20$ K, species differ only in mass
- Predict phonon properties and thermal conductivity
- MD simulations and lattice dynamics calculations
- Perfect and mixed interfaces



Phonon Lifetimes



More Phonon Lifetimes



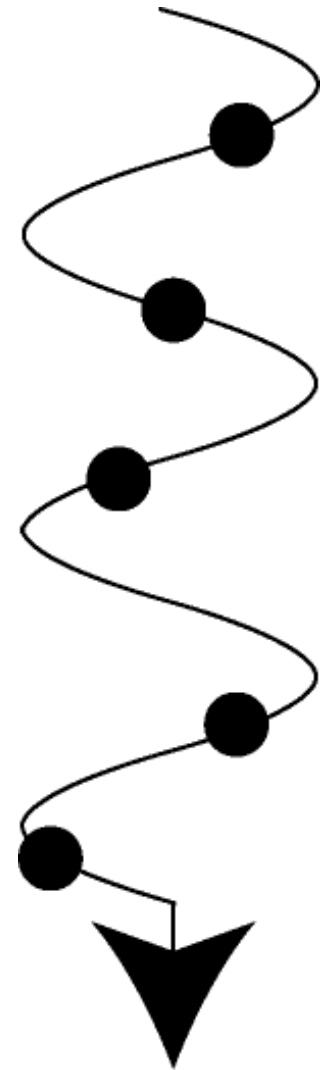
Huberman, Larkin, McGaughey & Amon, *Physical Review B* **88**, 155311 (2013).

Phonon Transport in Superlattices

- Superlattice dispersion always valid for perfect systems
- Interface mixing affects high frequency (short wavelength) modes
 - Superlattice dispersion a good approximation for most modes
- Bulk dispersion only a good approximation when period length \gg wavelength (mode dependent effect)

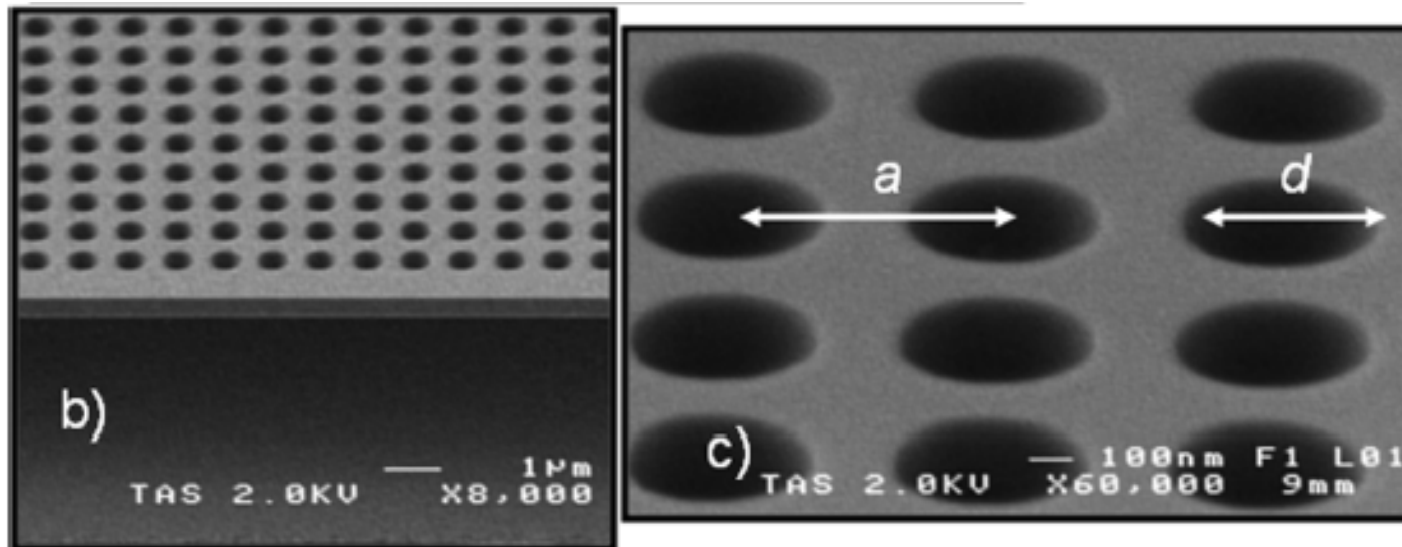
Outline

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Objective

Predict the thermal conductivity of a silicon structure like this:



in a few seconds.

Atomic
Scale

Density Functional
Theory



Force Constants



Lattice Dynamics
Calculations



Phonon Frequencies
& Mean Free Paths



Boltzmann Transport Equation

Boundary
Scattering
Model

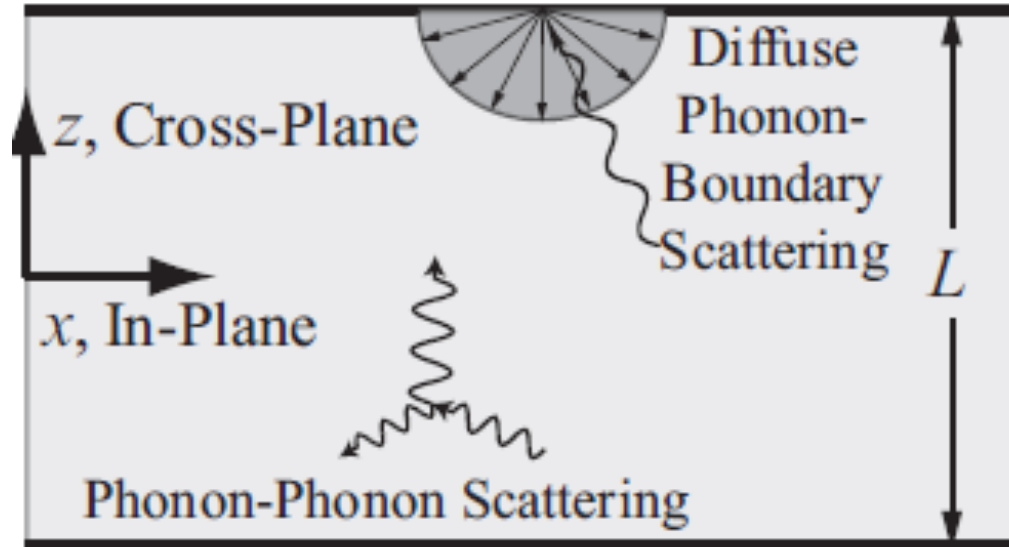


Thermal Conductivity

Meso-Scale



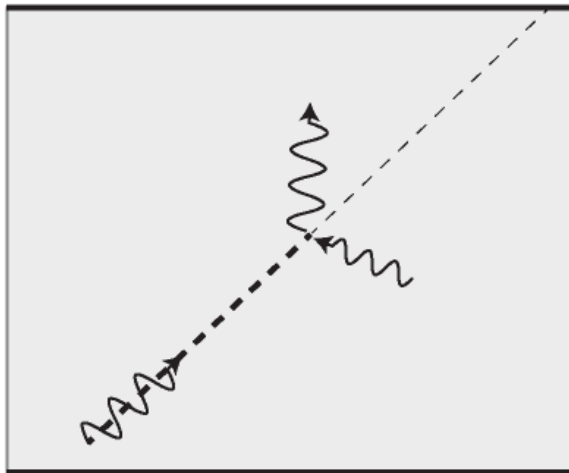
Thin Film Model



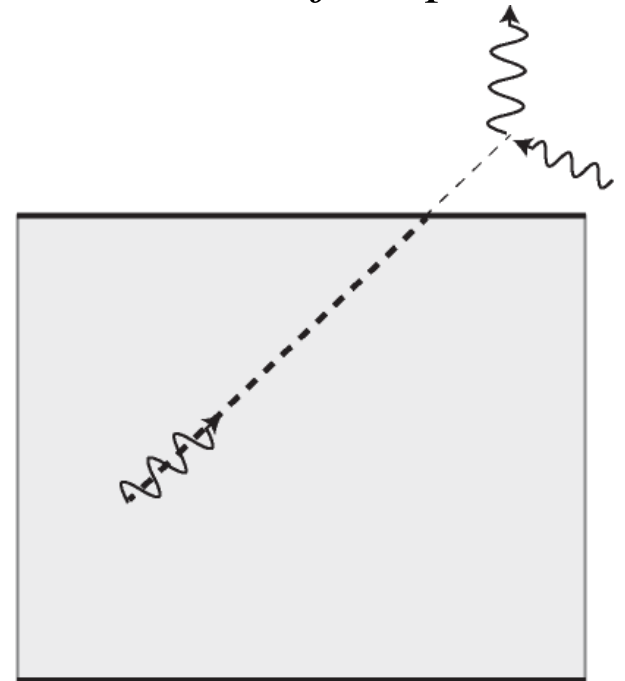
Random Sampling of Free Paths

- For every phonon mode, do the following 1,000 times:
 1. Phonon-phonon free path from a Poisson distribution.
 2. Randomly select a starting point. Use group velocity vector to calculate phonon-boundary free path.
 3. Smaller of these two quantities is the nanostructure free path
- Average 1,000 nanostructure *free paths* to give the *mean free path*.

McGaughey and
Jain, *APL* **100**,
061911 (2012).

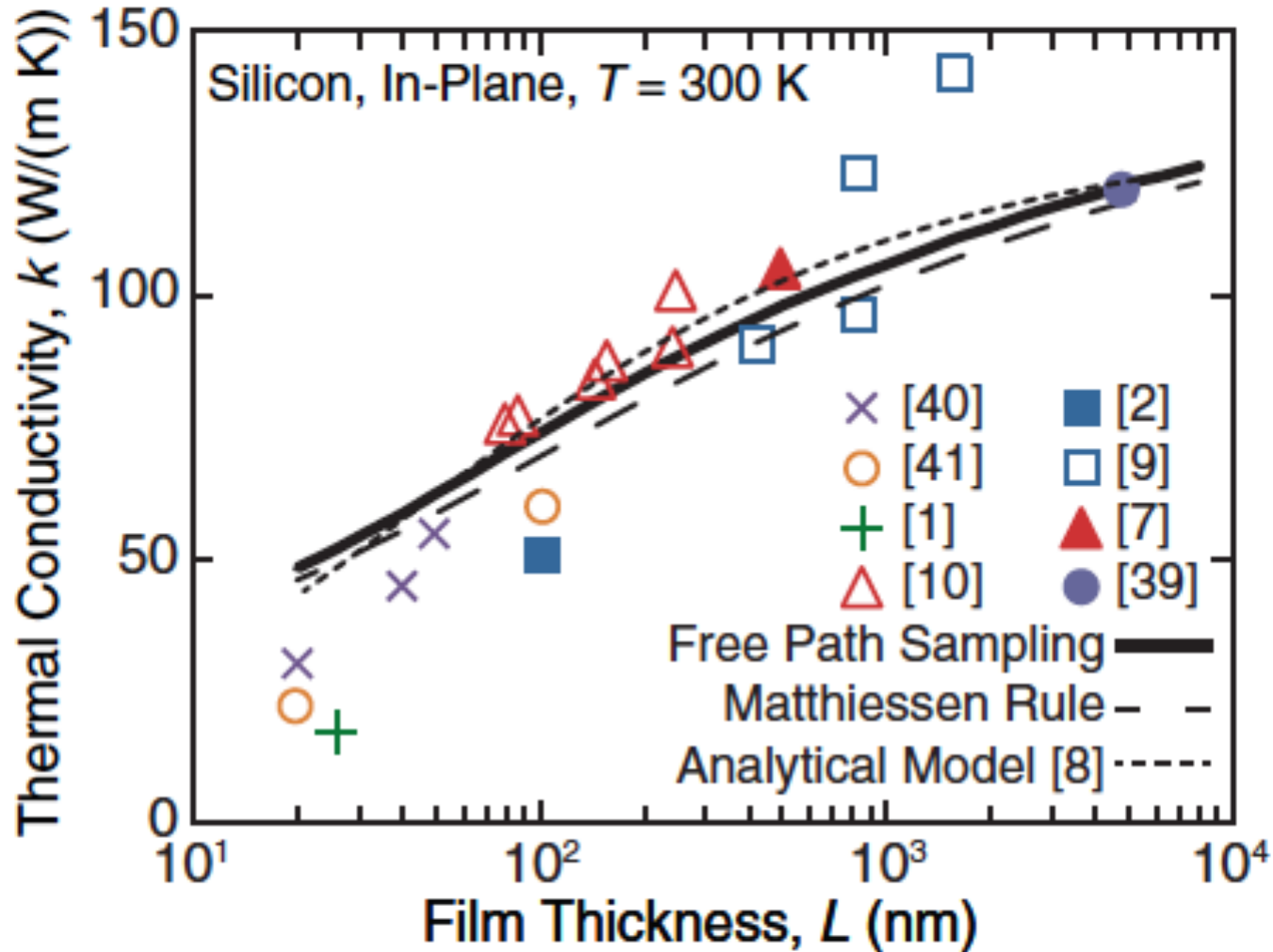


Limited by Phonon-Phonon



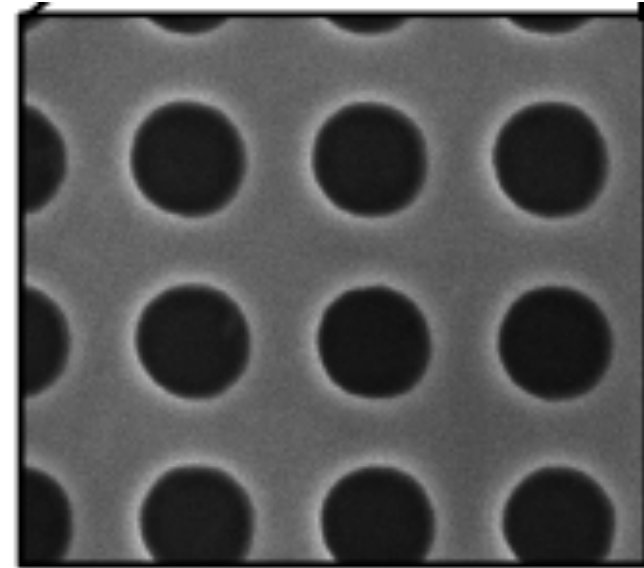
Limited by Phonon-Boundary

In-Plane: Comparison to Experiments

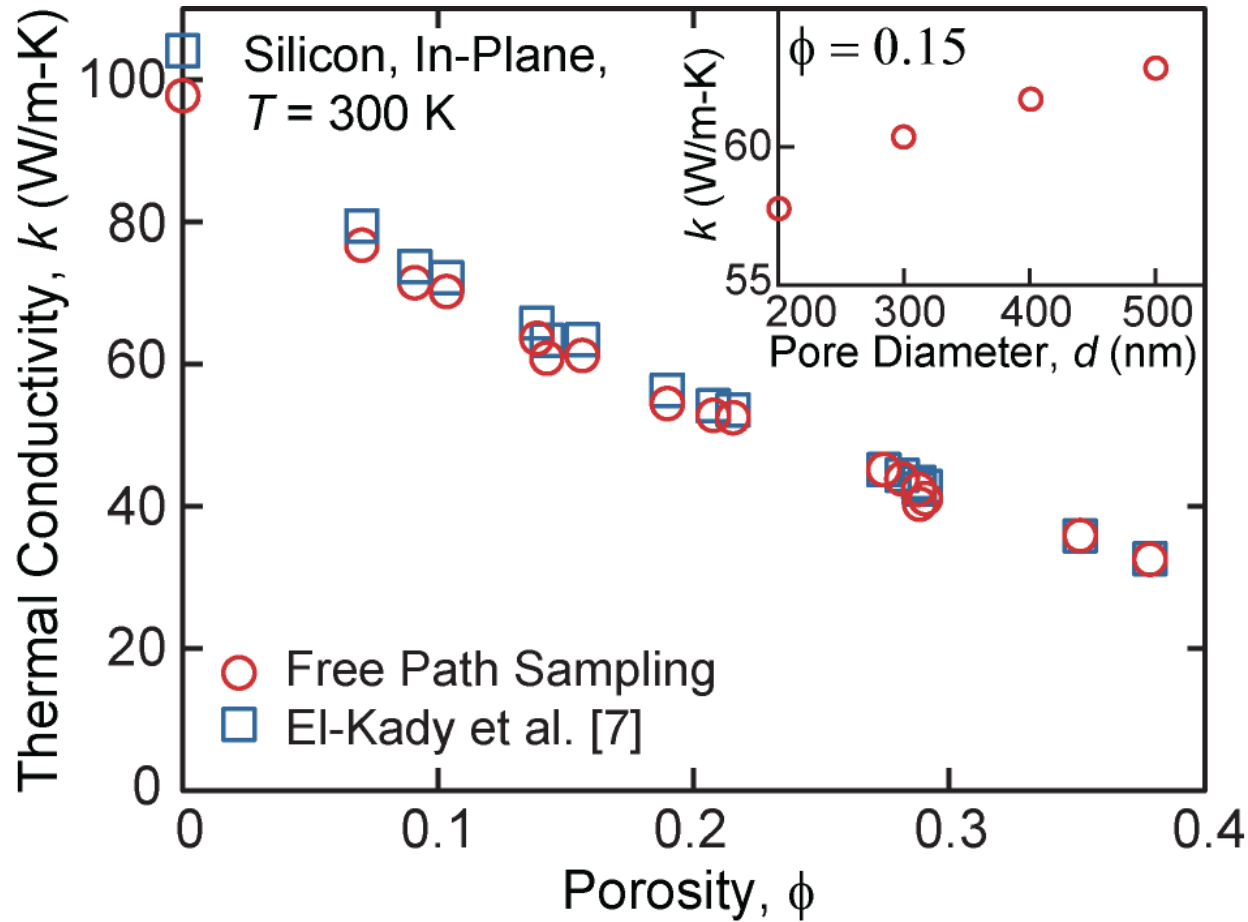


Sandia: Experimental Measurements @ 300 K

- In-Plane Measurements: 16 samples, 500 nm thick
 - Pore separation: 500-900 nm
 - Pore diameter: 213-535 nm
 - Porosity: 0.07-0.38
 - Steady-state measurement
 - SAND2012-0127
- Cross-Plane Measurements: 4 samples, 500 nm thick
 - Pore separation: 500-800 nm
 - Pore diameter: 300-400 nm
 - Porosity: 0.20-0.28
 - Time-domain thermoreflectance
 - Hopkins et al., *Nano Letters* **11**, 107 (2011)

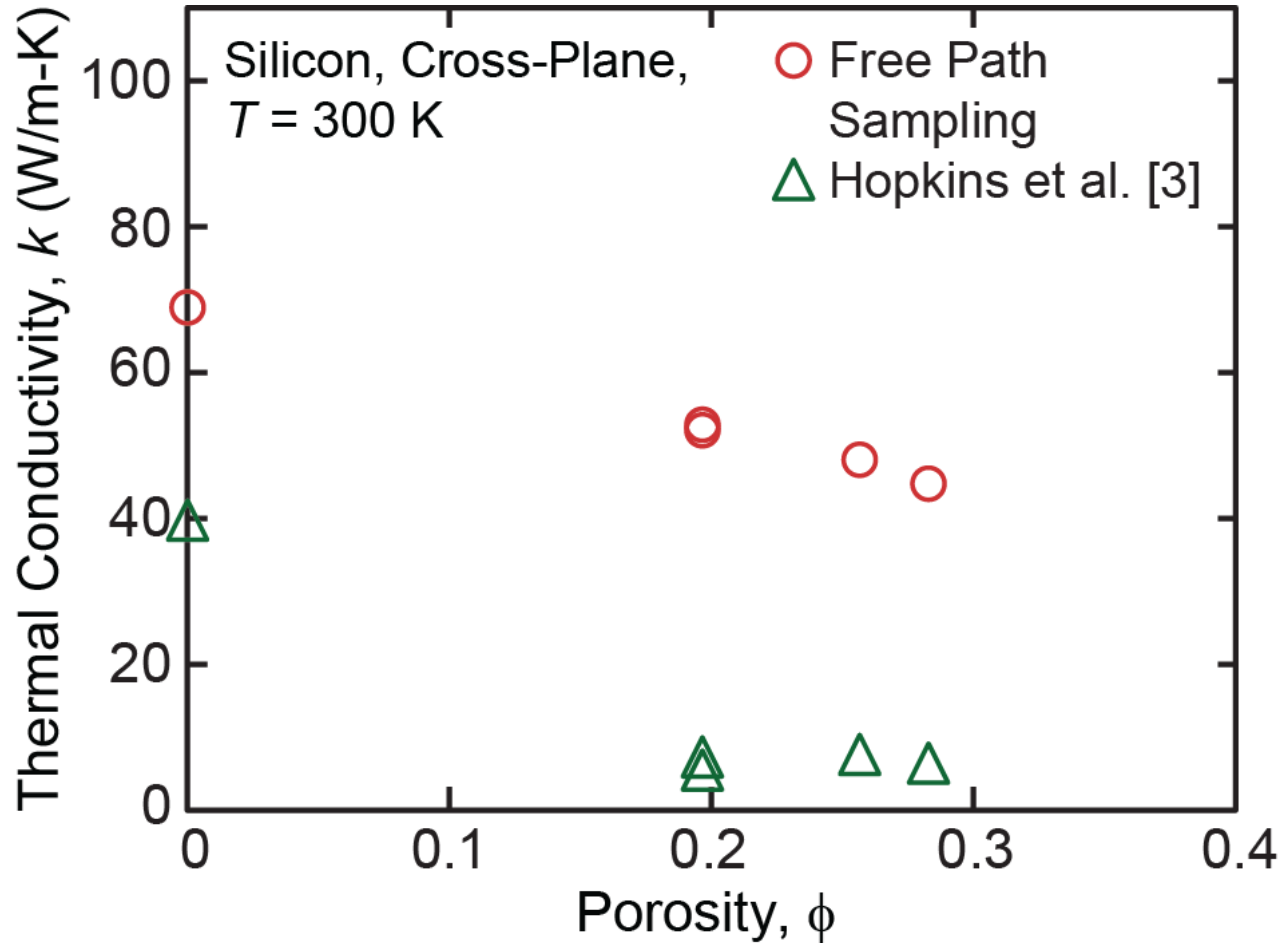


In-Plane Comparison



No evidence of coherent effects.

Cross-Plane Comparison

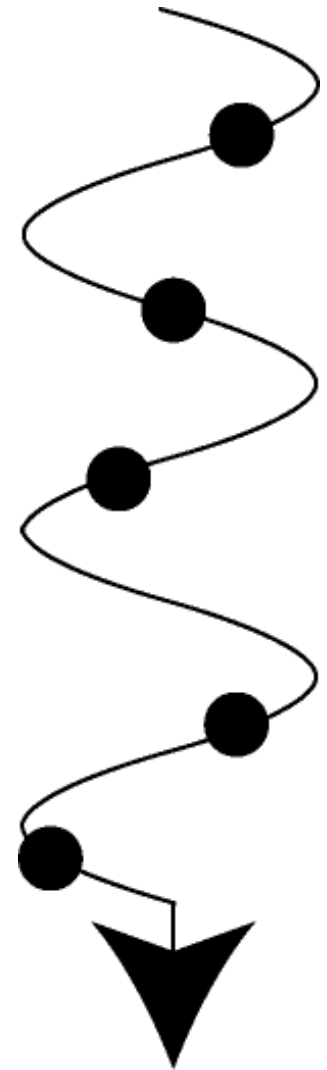


Phonon Transport in Porous Films

- Phonon properties obtained from first-principles can predict the measured thermal conductivities of silicon thin films.
- No evidence for coherent transport in in-plane direction for porous films.
- Unexplained cross-plane porous film thermal conductivities.

Outline

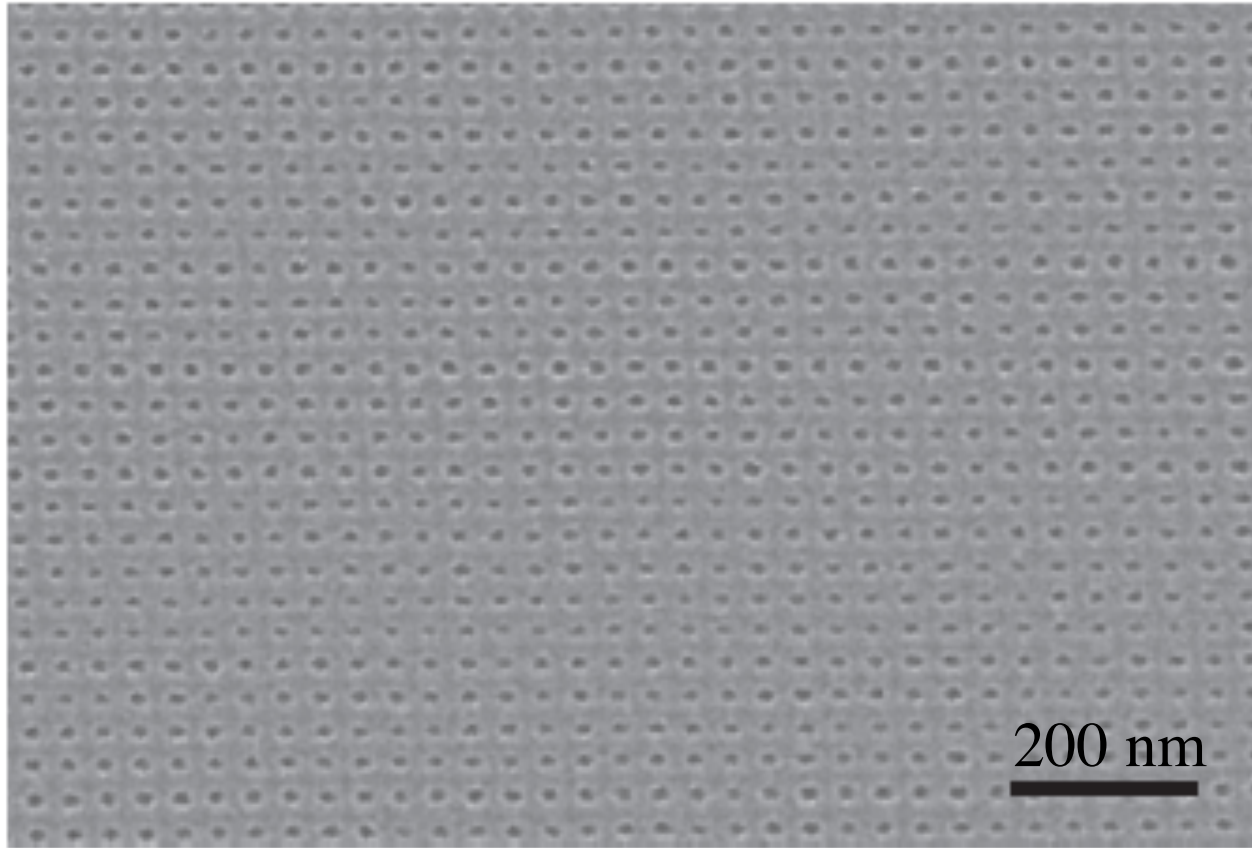
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Summary

- “Coherent” phonons follow dispersion of secondary periodicity
 - Relevant length scale: wavelength (<10 nm at 300 K)
 - Evidence in experimental and modeling on high-quality superlattices
- “Incoherent” phonons scatter with boundaries
 - Interface or free surface
 - Relevant length scale: mean free path (<10 μm at 300 K in Si)

Bridge Length Scales to Promote Coherence



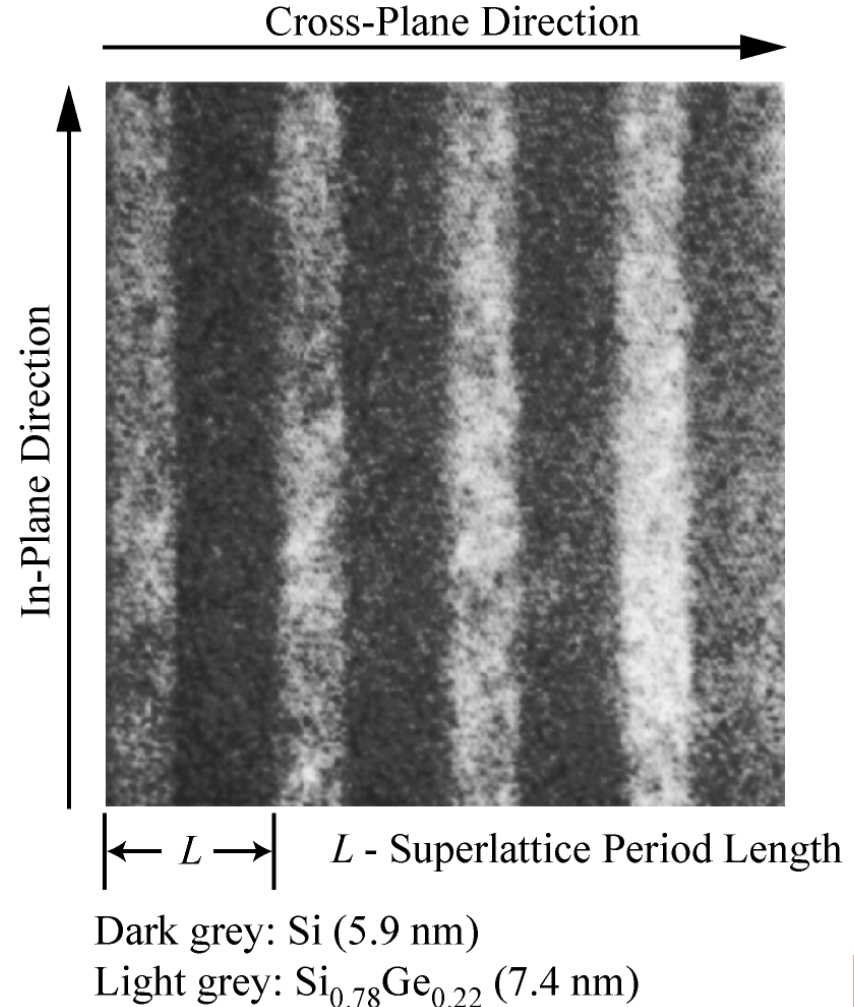
But what about variability in the pore size and surface roughness?
Use temperature to adjust what phonon wavelengths are important.

Semiconductor superlattices

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- Periodic, composite material with layers as thin as 1-10 nanometers.
- *Phonons* (quantized lattice vibrations) are the dominant thermal energy carriers.
- The electrical energy is carried by either *electrons* or *holes*.
- Phonon scattering at interfaces reduces k without degrading the charge transport, leading to high ZT .

$$ZT = \frac{S^2 \sigma}{k} T$$



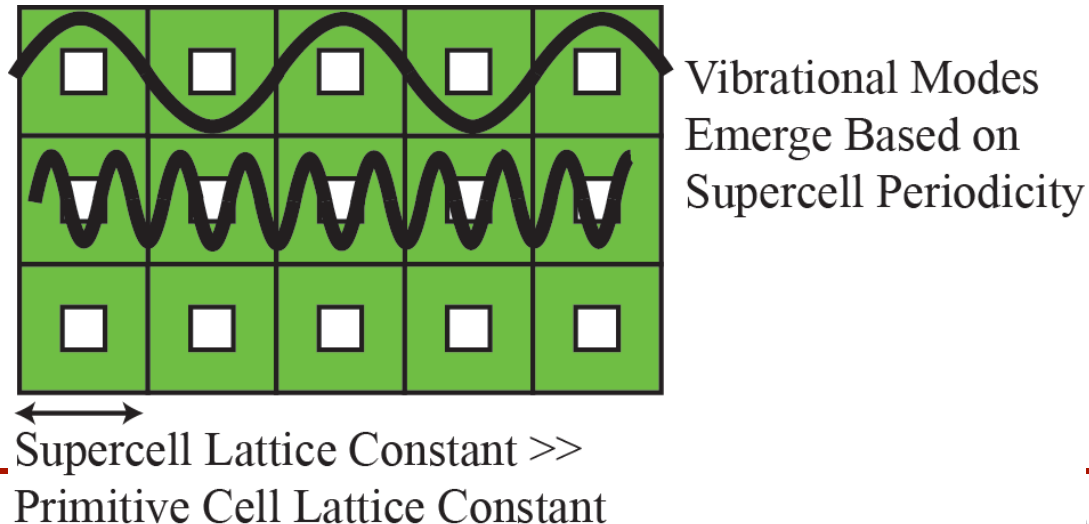
Interest in Porous Films

ENGINEERING: Thermoelectric Energy Conversion

$$ZT = \frac{S^2 \sigma T}{k_e + k_p}$$

Is it small?

SCIENCE: “Coherent” Phonon Effects and Role in Thermal Transport



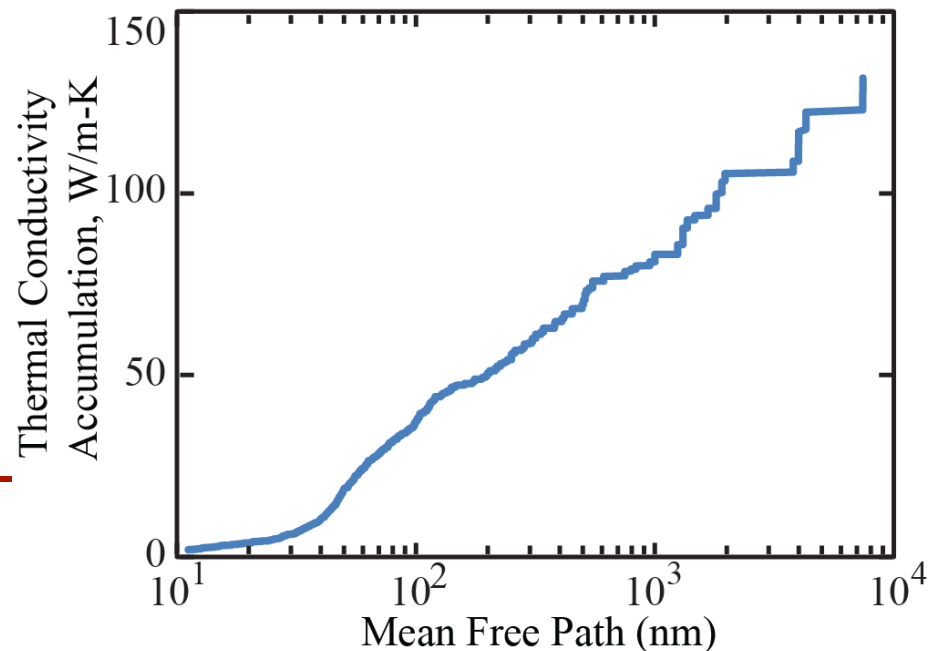
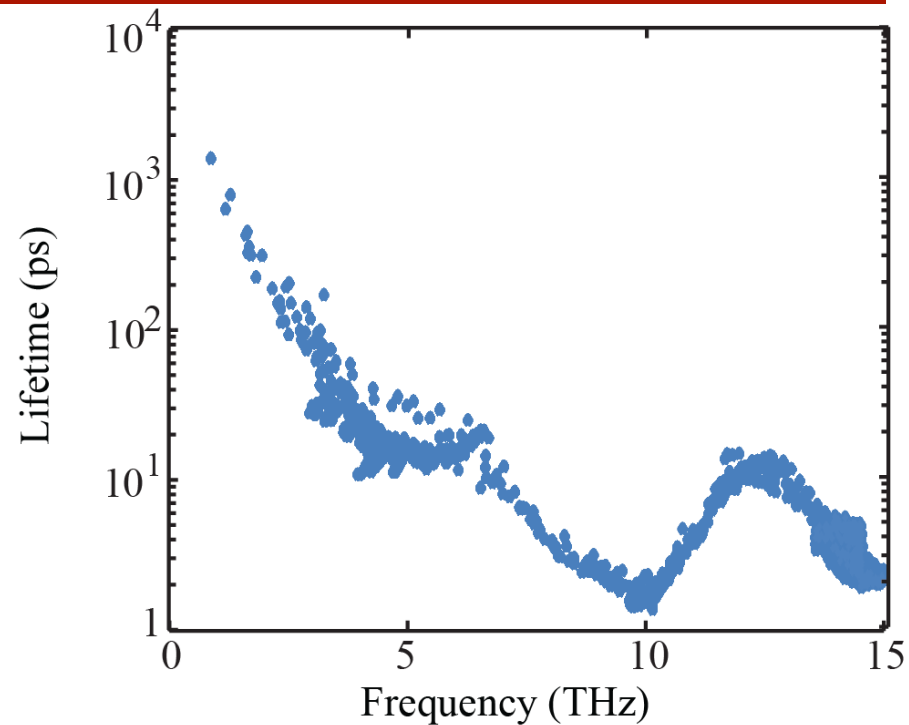
Bulk Silicon from First Principles

- Harmonic & anharmonic lattice dynamics calculations for 34,992 phonons in the first Brillouin zone
- $T = 300$ K

$$k_{theory} = 132 \text{ W/m-K}$$

$$k_{bulk, experiment} = 145 \text{ W/m-K}$$

Silicon phonon properties courtesy of Keivan Esfarjani, MIT.



Thermal Conductivity Prediction

Predicted from theory $\longrightarrow k_{CP,solid} = \sum_i c_{v,i} v_{g,i,CP}^2 \frac{\Lambda_i}{|\mathbf{v}_{g,i}|}$

Measured experimentally $\longrightarrow k_{CP,matrix} = k_{CP,solid} \times (1 - \phi)$, $\phi = \text{porosity}$

$$k_{IP,solid} = \sum_i c_{v,i} v_{g,i,IP}^2 \frac{\Lambda_i}{|\mathbf{v}_{g,i}|}$$

$$k_{IP,matrix} = k_{IP,solid} \times \frac{1 - \phi}{1 + \phi}$$

← Hashin Factor



Thermal Conductivity Accumulation

